

TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE

# 2SA1804

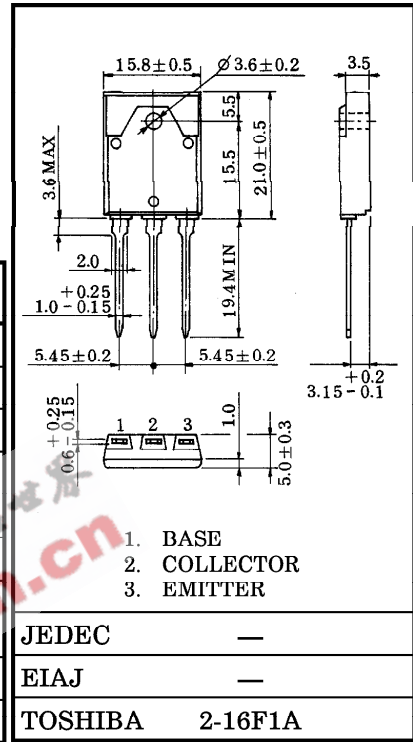
POWER AMPLIFIER APPLICATIONS

Unit in mm

- Complementary to 2SC4689
- Recommend for 55W High Fidelity Audio Frequency Amplifier output Stage.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V <sub>CB0</sub>	-120	V
Collector-Emitter Voltage		V <sub>CEO</sub>	-120	V
Emitter-Base Voltage		V <sub>EBO</sub>	-5	V
Collector Current	DC	I <sub>C</sub>	-8	A
	Pulse	I <sub>CP</sub>	-16	
Base Current		I <sub>B</sub>	-0.8	A
Collector Power Dissipation (Tc = 25°C)		P <sub>C</sub>	70	W
Junction Temperature		T <sub>j</sub>	150	°C
Storage Temperature Range		T <sub>stg</sub>	-55~150	°C



Weight : 5.8g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I <sub>CBO</sub>	V <sub>CB</sub> = -120V, I <sub>E</sub> = 0	—	—	-5.0	μA
Emitter Cut-off Current	I <sub>EBO</sub>	V <sub>EB</sub> = -5V, I <sub>C</sub> = 0	—	—	-5.0	μA
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = -50mA, I <sub>B</sub> = 0	-120	—	—	V
DC Current Gain	h <sub>FE</sub> (1) (Note)	V <sub>CE</sub> = -5V, I <sub>C</sub> = -1A	55	—	160	
	h <sub>FE</sub> (2)	V <sub>CE</sub> = -5V, I <sub>C</sub> = -4A	35	75	—	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = -6A, I <sub>B</sub> = -0.6A	—	-0.80	-2.0	V
Base-Emitter Voltage	V <sub>BE</sub>	V <sub>CE</sub> = -5V, I <sub>C</sub> = -4A	—	-0.97	-1.5	V
Transition Frequency	f <sub>T</sub>	V <sub>CE</sub> = -5V, I <sub>C</sub> = -1A	—	30	—	MHz
Collector Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0, f = 1MHz	—	420	—	pF

Note : h<sub>FE</sub>(1) Classification R : 55~110, O : 80~160

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